



## **Global Communication Semiconductors, LLC**

Corporate & Foundry

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Job Title: **Device/Process Integration Engineer**  
Opened: 2/23/18  
Job Req. #0643  
Department: RF and Power Technology  
Status: Full-Time/ Exempt  
Shift: Day

### **Job Description**

- Responsible for GaN HEMT process development and yield improvement efforts, including 1.0 um, 0.5 um and 0.25, 0.15 um processes for RF and power electronics applications.
- Responsible for device characterization and process qualifications
- Support trouble-shooting and yield improvement in pHEMT, HFET and MESFET production processes.

### **Job Requirements**

- PhD in Electrical Engineering degree, Physics or Material Science
- 3-5 years of industry experience in a semiconductor wafer fab environment
- Familiarity with compound semiconductor devices, processing and handling a plus